

Triacs

BT137S series

GENERAL DESCRIPTION

Passivated triacs in a plastic envelope, suitable for surface mounting, intended for use in applications requiring high bidirectional transient and blocking voltage capability and high thermal cycling performance. Typical applications include motor control, industrial and domestic lighting, heating and static switching.

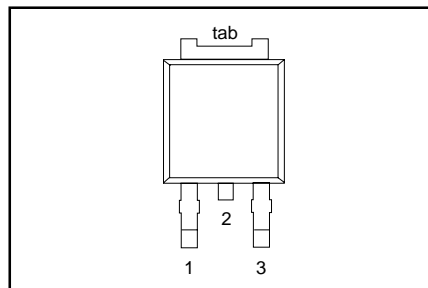
QUICK REFERENCE DATA

| SYMBOL | PARAMETER | MAX. | MAX. | UNIT |
|--------------|--------------------------------------|------|------|------|
| V_{DRM} | Repetitive peak off-state voltages | 600 | 800 | V |
| $I_{T(RMS)}$ | RMS on-state current | 8 | 8 | A |
| I_{TSM} | Non-repetitive peak on-state current | 65 | 65 | A |

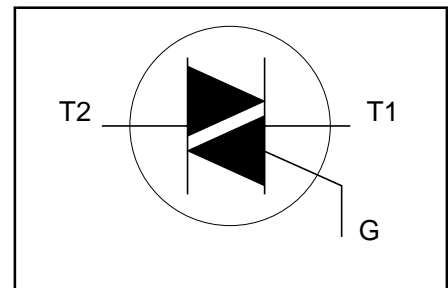
PINNING - SOT428

| PIN | DESCRIPTION |
|-----|-------------|
| 1 | MT1 |
| 2 | MT2 |
| 3 | gate |
| tab | MT2 |

PIN CONFIGURATION



SYMBOL



LIMITING VALUES

Limiting values in accordance with the Absolute Maximum System (IEC 134).

| SYMBOL | PARAMETER | CONDITIONS | MIN. | MAX. | | UNIT |
|--------------|--|--|------|--------------------------|-------------|------------------|
| | | | | -600 600 ¹ | -800 800 | |
| V_{DRM} | Repetitive peak off-state voltages | | - | -600 600 ¹ | -800 800 | V |
| $I_{T(RMS)}$ | RMS on-state current | full sine wave; $T_{mb} \leq 102^\circ\text{C}$ | - | 8 | | A |
| I_{TSM} | Non-repetitive peak on-state current | full sine wave; $T_j = 25^\circ\text{C}$ prior to surge $t = 20\text{ ms}$ | - | 65 | | A |
| I^2t | I^2t for fusing | $t = 16.7\text{ ms}$ | - | 71 | | A |
| dl/dt | Repetitive rate of rise of on-state current after triggering | $t = 10\text{ ms}$ $I_{TM} = 12\text{ A}; I_G = 0.2\text{ A}; dl_G/dt = 0.2\text{ A}/\mu\text{s}$ | - | 21 | | A ² s |
| I_{GM} | Peak gate current | T2+ G+ | - | 50 | | A/ μs |
| V_{GM} | Peak gate voltage | T2+ G- | - | 50 | | A/ μs |
| P_{GM} | Peak gate power | T2- G- | - | 50 | | A/ μs |
| $P_{G(AV)}$ | Average gate power | T2- G+ | - | 10 | | A/ μs |
| T_{stg} | Storage temperature | | - | 2 | | A |
| T_j | Operating junction temperature | | - | 5 | | V |
| | | | - | 5 | | W |
| | | over any 20 ms period | - | 0.5 | | W |
| | | | -40 | 150 | | $^\circ\text{C}$ |
| | | | - | 125 | | $^\circ\text{C}$ |

¹ Although not recommended, off-state voltages up to 800V may be applied without damage, but the triac may switch to the on-state. The rate of rise of current should not exceed 6 A/ μs .

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THERMAL RESISTANCES

| SYMBOL | PARAMETER | CONDITIONS | MIN. | TYP. | MAX. | UNIT |
|----------------|---|---|------|------|------|------|
| $R_{th\ j-mb}$ | Thermal resistance junction to mounting base | full cycle | - | - | 2.0 | K/W |
| $R_{th\ j-a}$ | Thermal resistance junction to ambient | half cycle pcb (FR4) mounted; footprint as in Fig.14 | - | - | 2.4 | K/W |
| | | | - | 75 | - | K/W |

STATIC CHARACTERISTICS

 $T_j = 25\text{ }^\circ\text{C}$ unless otherwise stated

| SYMBOL | PARAMETER | CONDITIONS | MIN. | TYP. | MAX. | | | UNIT |
|----------|---------------------------|--|------|------|------|------|------|------|
| I_{GT} | Gate trigger current | BT137S- $V_D = 12\text{ V}; I_T = 0.1\text{ A}$ | - | - | ... | ...F | ...G | |
| | | T2+ G+ | - | 5 | 35 | 25 | 50 | mA |
| | | T2+ G- | - | 8 | 35 | 25 | 50 | mA |
| | | T2- G- | - | 11 | 35 | 25 | 50 | mA |
| | | T2- G+ | - | 30 | 70 | 70 | 100 | mA |
| I_L | Latching current | $V_D = 12\text{ V}; I_{GT} = 0.1\text{ A}$ | - | - | - | - | - | |
| | | T2+ G+ | - | 7 | 30 | 30 | 45 | mA |
| | | T2+ G- | - | 16 | 45 | 45 | 60 | mA |
| | | T2- G- | - | 5 | 30 | 30 | 45 | mA |
| | | T2- G+ | - | 7 | 45 | 45 | 60 | mA |
| I_H | Holding current | $V_D = 12\text{ V}; I_{GT} = 0.1\text{ A}$ | - | 5 | 20 | 20 | 40 | mA |
| V_T | On-state voltage | $I_T = 10\text{ A}$ | - | 1.3 | 1.65 | | | V |
| V_{GT} | Gate trigger voltage | $V_D = 12\text{ V}; I_T = 0.1\text{ A}$ | - | 0.7 | 1.5 | | | V |
| | | $V_D = 400\text{ V}; I_T = 0.1\text{ A};$ $T_j = 125\text{ }^\circ\text{C}$ | 0.25 | 0.4 | - | | | V |
| I_D | Off-state leakage current | $V_D = V_{DRM(max)};$ $T_j = 125\text{ }^\circ\text{C}$ | - | 0.1 | 0.5 | | | mA |

DYNAMIC CHARACTERISTICS

 $T_j = 25\text{ }^\circ\text{C}$ unless otherwise stated

| SYMBOL | PARAMETER | CONDITIONS | MIN. | | | TYP. | MAX. | UNIT |
|---------------|---|---|------|------|------|------|------|------------------|
| dV_D/dt | Critical rate of rise of off-state voltage | BT137S- $V_{DM} = 67\% V_{DRM(max)};$ $T_j = 125\text{ }^\circ\text{C};$ exponential waveform; gate open circuit | ... | ...F | ...G | 250 | - | V/ μs |
| dV_{com}/dt | Critical rate of change of commutating voltage | $V_{DM} = 400\text{ V}; T_j = 95\text{ }^\circ\text{C};$ $I_{T(RMS)} = 8\text{ A};$ $dl_{com}/dt = 3.6\text{ A/ms};$ gate open circuit | - | - | 10 | 20 | - | V/ μs |
| t_{gt} | Gate controlled turn-on time | $I_{TM} = 12\text{ A}; V_D = V_{DRM(max)};$ $I_G = 0.1\text{ A}; dl_G/dt = 5\text{ A}/\mu\text{s}$ | - | - | - | 2 | - | μs |

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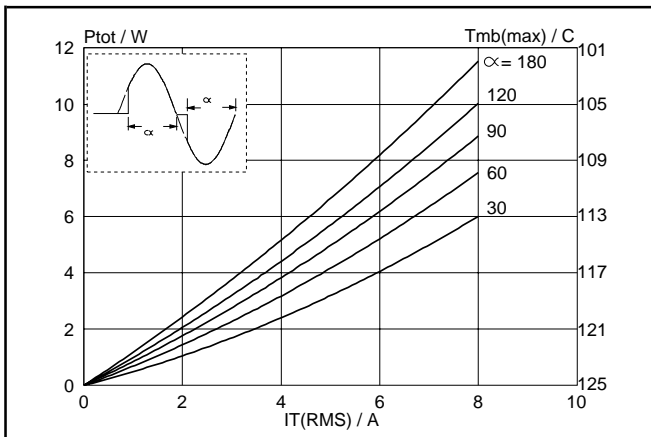


Fig.1. Maximum on-state dissipation, P_{tot} , versus rms on-state current, $I_{T(RMS)}$, where $\alpha =$ conduction angle.

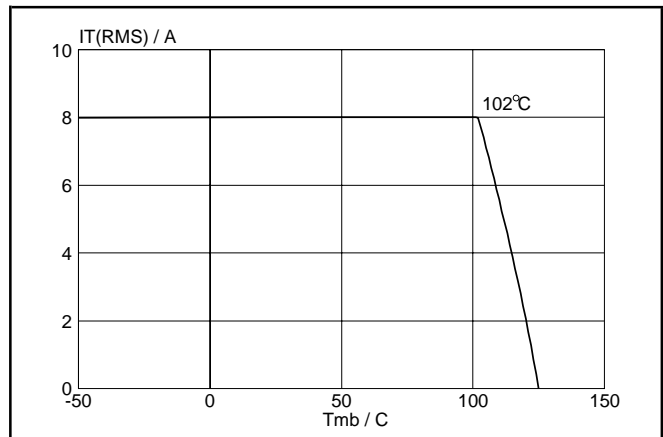


Fig.4. Maximum permissible rms current $I_{T(RMS)}$, versus mounting base temperature T_{mb} .

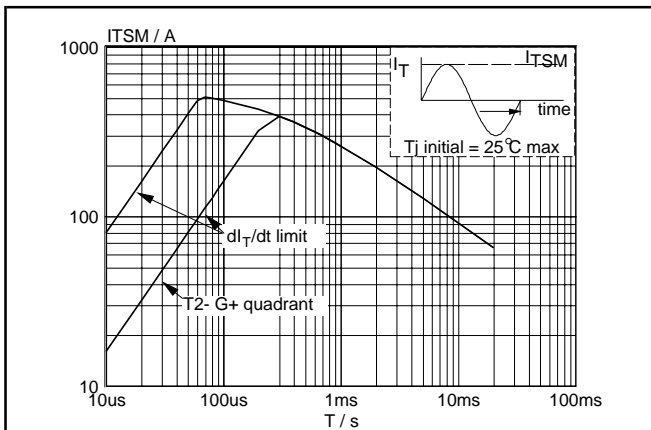


Fig.2. Maximum permissible non-repetitive peak on-state current I_{TSM} , versus pulse width t_p , for sinusoidal currents, $t_p \leq 20ms$.

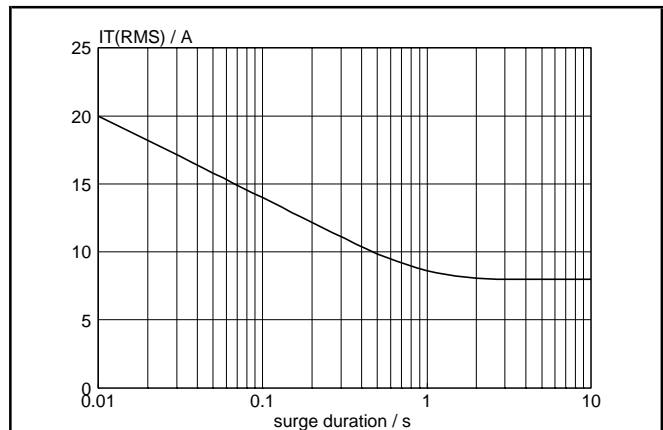


Fig.5. Maximum permissible repetitive rms on-state current $I_{T(RMS)}$, versus surge duration, for sinusoidal currents, $f = 50$ Hz; $T_{mb} \leq 102^\circ\text{C}$.

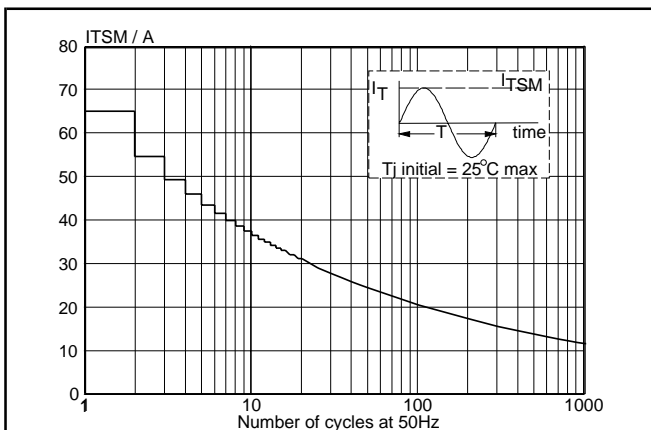


Fig.3. Maximum permissible non-repetitive peak on-state current I_{TSM} , versus number of cycles, for sinusoidal currents, $f = 50$ Hz.

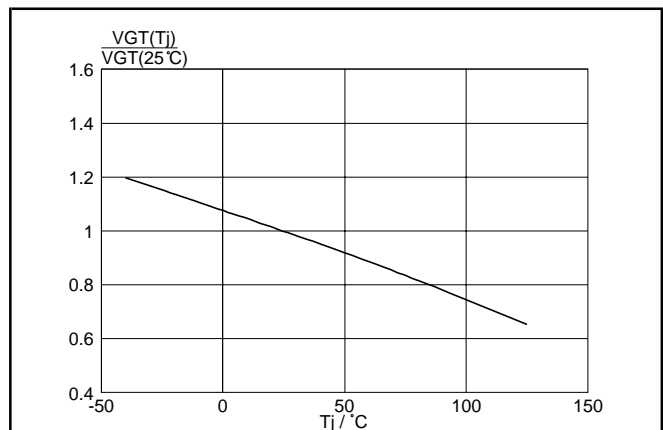
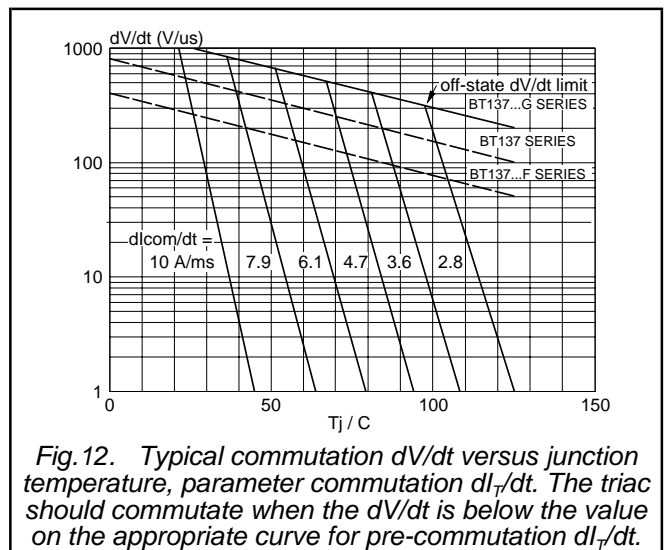
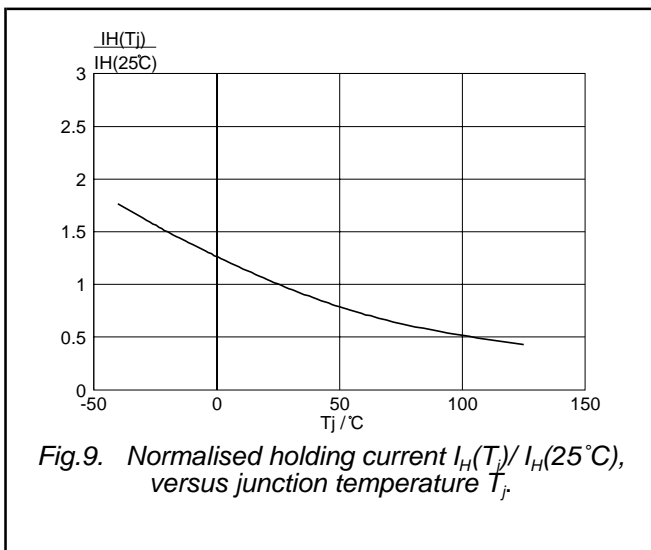
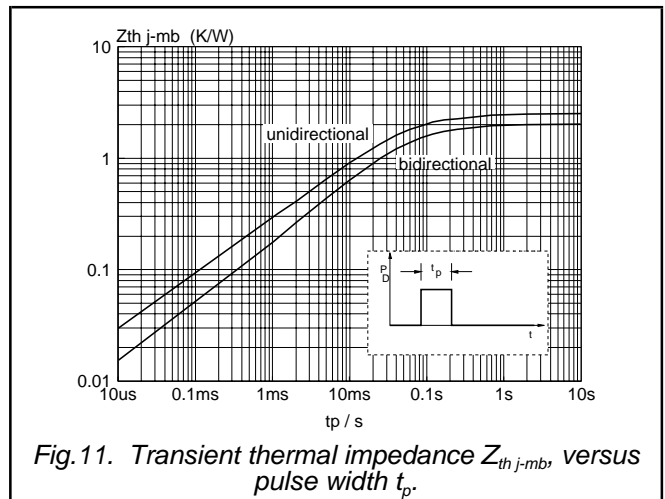
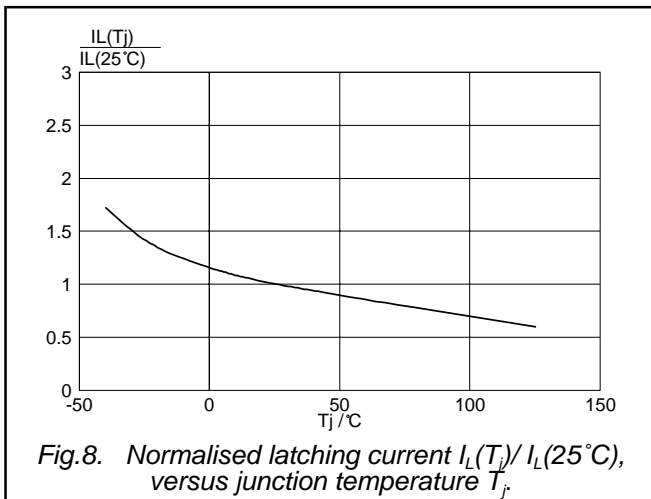
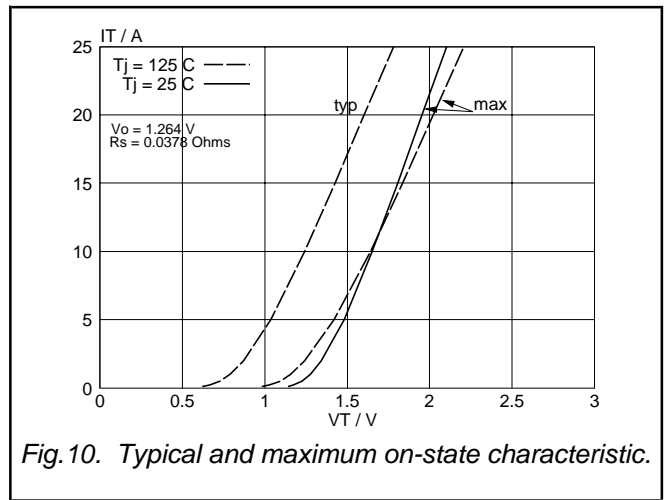
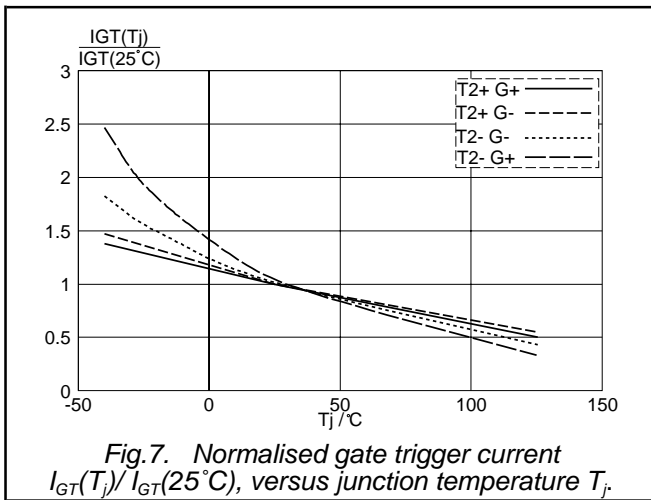


Fig.6. Normalised gate trigger voltage $V_{GT}(T_j) / V_{GT}(25^\circ\text{C})$, versus junction temperature T_j .

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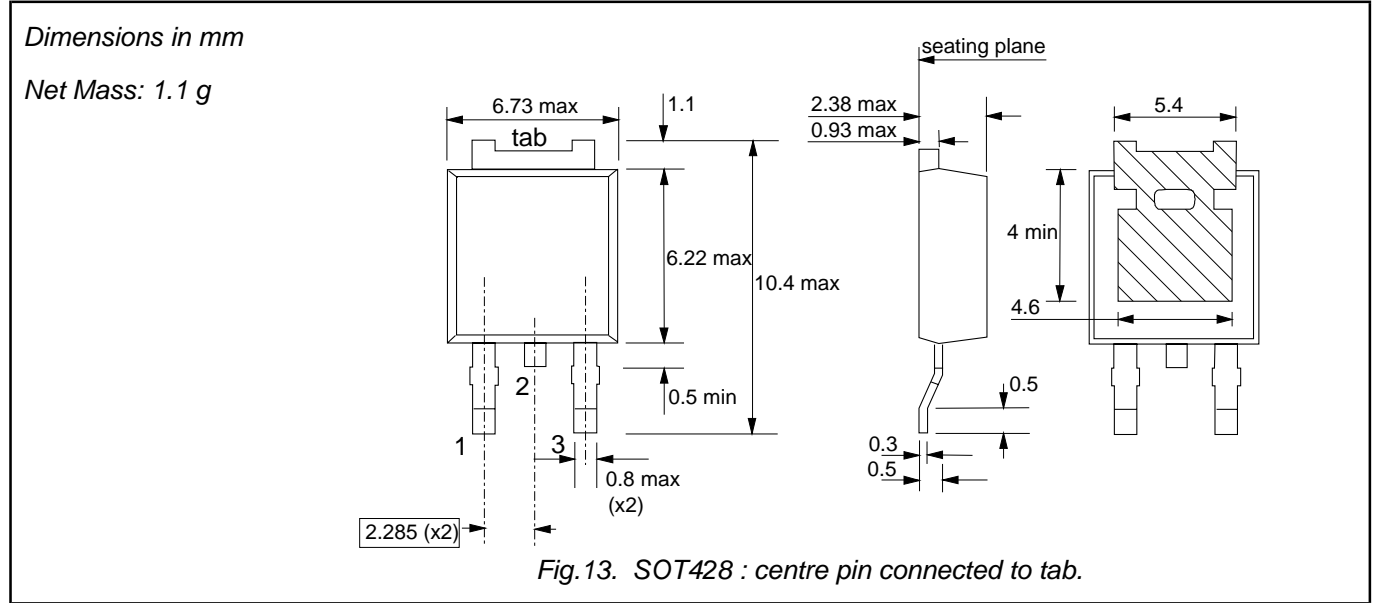
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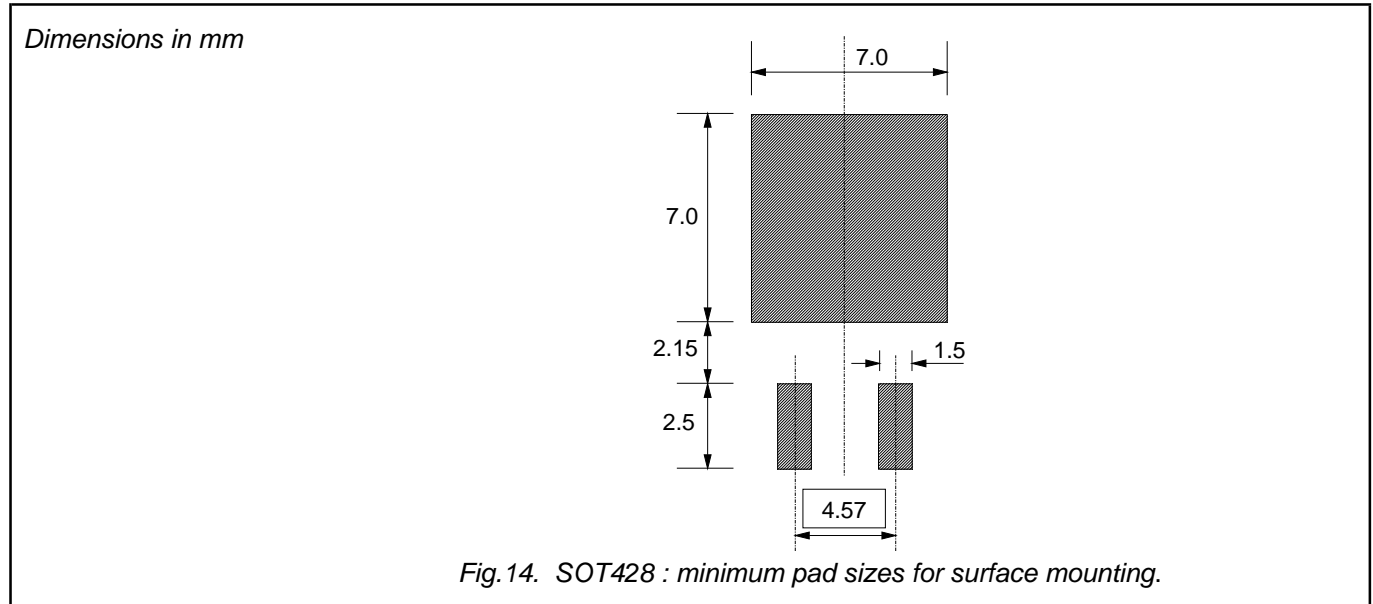
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MECHANICAL DATA



MOUNTING INSTRUCTIONS



Notes

1. Plastic meets UL94 V0 at 1/8".

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DEFINITIONS

| DATA SHEET STATUS | | |
|--|-----------------------------------|---|
| DATA SHEET STATUS² | PRODUCT STATUS³ | DEFINITIONS |
| Objective data | Development | This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice |
| Preliminary data | Qualification | This data sheet contains data from the preliminary specification. Supplementary data will be published at a later date. Philips Semiconductors reserves the right to change the specification without notice, in order to improve the design and supply the best possible product |
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| Limiting values | | |
| Limiting values are given in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of this specification is not implied. Exposure to limiting values for extended periods may affect device reliability. | | |
| Application information | | |
| Where application information is given, it is advisory and does not form part of the specification. | | |
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